Product data sheet

1. General description

Dual ultrafast power diode in a SOT429 (3-lead TO-247) plastic package.

2. Features and benefits

- Very low on-state loss
- Fast switching
- · Soft recovery characteristic minimizes power consuming oscillations
- · High thermal cycling performance
- · Low thermal resistance

3. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _R	reverse voltage	DC	-	-	400	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 104 °C; square-wave pulse; per diode; Fig. 1; Fig. 2; Fig. 3	-	-	15	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode; Fig. 4	-	-	170	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode	-	-	185	А
Static chara	acteristics					
V _F	forward voltage	I _F = 15 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.08	1.25	V
		I _F = 30 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.15	1.36	V
		I _F = 15 A; T _j = 150 °C; <u>Fig. 6</u>	-	0.95	1.12	V
Dynamic ch	naracteristics					
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/µs}$; $T_j = 25 \text{ °C}$; Fig. 7	-	35	60	ns

4. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1		A1 A2
2	K	cathode		A1
3	A2	anode 2		K sym125
mb	К	mounting base; cathode		
			TO-247 (SOT429)	

5. Ordering information

Table 3. Ordering information

Type number	Package						
	Name	Description	Version				
BYV74W-400	TO-247	plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 3 lead TO-247	SOT429				

6. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	400	V
V_{RWM}	crest working reverse voltage		-	400	V
V_R	reverse voltage	DC; T _{mb} ≤ 136 °C	-	400	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 104 °C; square-wave pulse; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	15	А
I _{O(AV)}	average output current	δ = 0.5 ; T _{mb} ≤ 94 °C; square-wave pulse; both diodes conducting	-	30	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode; Fig. 4	-	170	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode	-	185	А
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

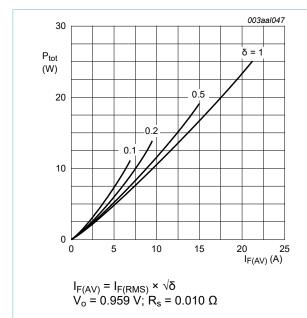


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; per diode; maximum values

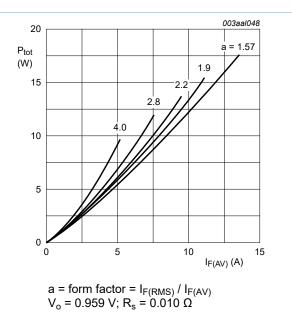


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; per diode; maximum values

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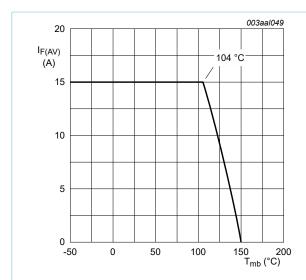


Fig. 3. Average forward current as a function of mounting base temperature; per diode; maximum values

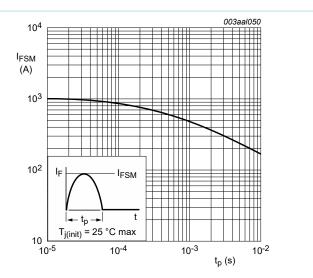


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; per diode; maximum values

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7. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to	with heatsink compound; per diode; Fig. 5	 -	-	2.4	K/W
	mounting base	with heatsink compound; both diodes conducting	-	-	1.4	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	_	45	-	K/W

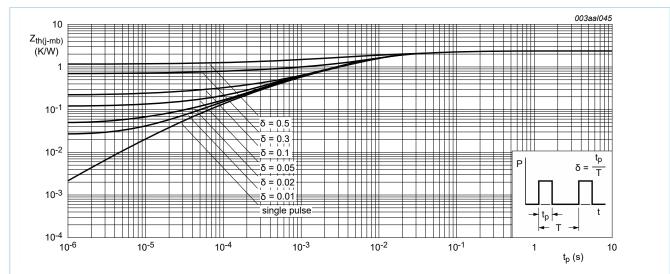


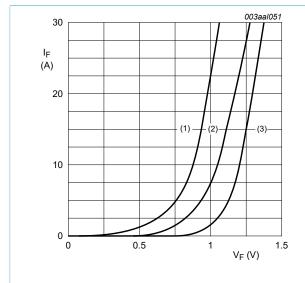
Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse width; per diode; maximum values

8. Characteristics

Table 6. Characteristics

characteristics are per diode unless otherwise stated

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _F	forward voltage	I _F = 15 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.08	1.25	V
		I _F = 30 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.15	1.36	V
		I _F = 15 A; T _j = 150 °C; <u>Fig. 6</u>	-	0.95	1.12	V
I _R	reverse current	V _R = 400 V; T _j = 25 °C	-	10	50	μA
		V _R = 400 V; T _j = 100 °C	-	0.3	0.8	mA
Dynamic cl	haracteristics					
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; $\frac{\text{Fig. 7}}{}$	-	35	60	ns
I _{RM}	peak reverse recovery current	$I_F = 10 \text{ A; } V_R = 30 \text{ V; } dI_F/dt = 50 \text{ A/}\mu\text{s;}$ $T_j = 100 ^{\circ}\text{C; } \underline{\text{Fig. 7}}$	-	4.2	5.2	Α
Q _r	recovered charge	$I_F = 2 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 20 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; Fig. 7	-	40	60	nC
V_{FR}	forward recovery voltage	$I_F = 10 \text{ A}$; $dI_F/dt = 10 \text{ A}/\mu\text{s}$; $T_j = 25 \text{ °C}$; Fig. 8	-	2.5	-	V



 $V_o = 0.959 \text{ V}; R_s = 0.010 \Omega$

(1) $T_j = 150 \,^{\circ}\text{C}$; typical values (2) $T_j = 150 \,^{\circ}\text{C}$; maximum values (3) $T_j = 25 \,^{\circ}\text{C}$; maximum values



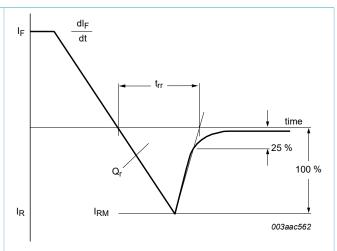
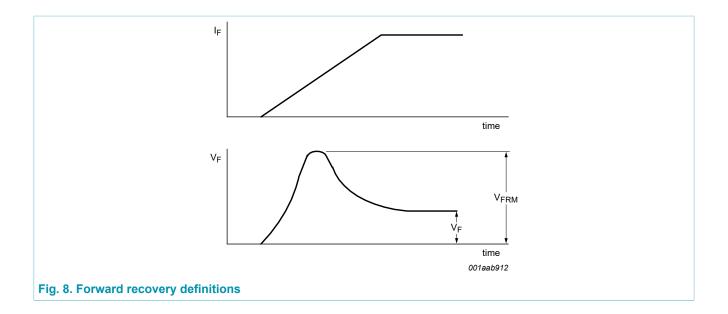


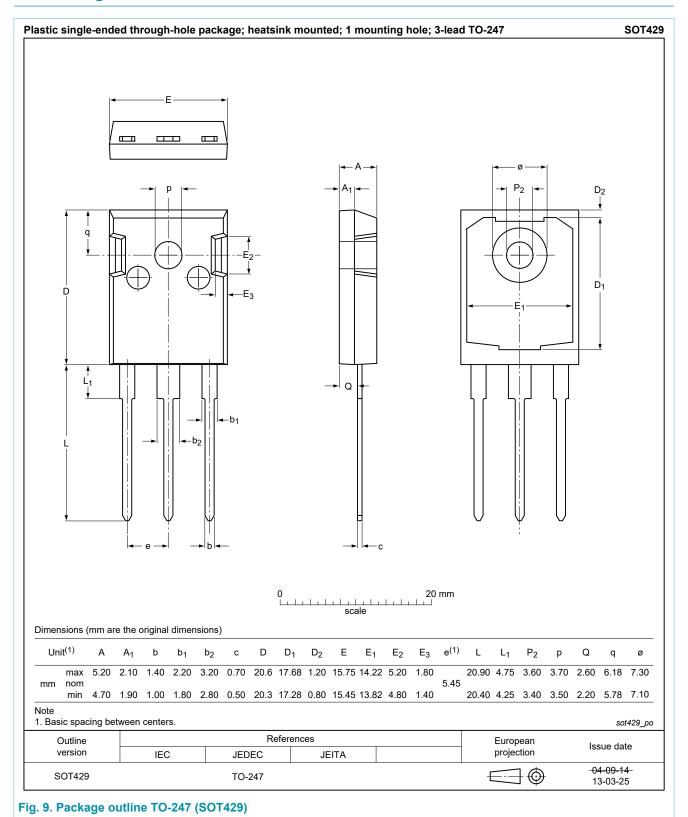
Fig. 7. Reverse recovery definitions; ramp recovery

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9. Package outline



10. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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